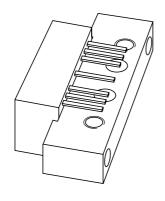
### **DISCRETE SEMICONDUCTORS**

# DATA SHEET



# CGY887B 860 MHz, 27.8 dB gain push-pull amplifier

**Product specification** 

2001 Nov 27





## 860 MHz, 27.8 dB gain push-pull amplifier

#### **CGY887B**

#### **FEATURES**

- · Excellent linearity
- High gain
- Extremely low noise
- · Excellent return loss properties
- Rugged construction
- Gold metallization ensures excellent reliability.

#### **APPLICATIONS**

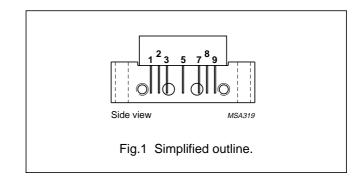
• CATV systems operating in the 40 to 870 MHz frequency range.

#### **DESCRIPTION**

Hybrid dynamic range amplifier module in a SOT115J package operating at a voltage supply of 24 V (DC), employing both GaAs and Si dies.

#### **PINNING - SOT115J**

PIN	DESCRIPTION
1	input
2, 3	common
5	+V <sub>B</sub>
7, 8	common
9	output



#### **QUICK REFERENCE DATA**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Gp	power gain	f = 45 MHz	27.2	27.8	dB
		f = 870 MHz	28	29	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 24 V	295	325	mA

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER		MAX.	UNIT
V <sub>B</sub>	supply voltage	_	30	V
Vi	RF input voltage (single tone)		70	dBmV
T <sub>stg</sub>	storage temperature		+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

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#### **CHARACTERISTICS**

Bandwidth 45 to 870 MHz;  $V_B$  = 24 V;  $T_{mb}$  = 35 °C;  $Z_S$  =  $Z_L$  = 75  $\Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Gp	power gain	f = 45 MHz	27.2	27.5	27.8	dB
		f = 870 MHz	28	28.5	29	dB
SL	slope straight line	f = 45 to 870 MHz	0.5	1	1.5	dB
FL	flatness straight line	f = 45 to 100 MHz	-0.25	_	+0.25	dB
		f = 100 to 800 MHz	-0.5	_	+0.5	dB
		f = 800 to 870 MHz	-0.4	_	+0.1	dB
S <sub>11</sub>	input return losses	f = 40 to 80 MHz	24	_	_	dB
		f = 80 to 160 MHz	22	_	_	dB
		f = 160 to 320 MHz	19	_	_	dB
		f = 320 to 550 MHz	18	_	_	dB
		f = 550 to 650 MHz	17	_	_	dB
		f = 650 to 750 MHz	16	_	-	dB
		f = 750 to 870 MHz	14	_	_	dB
		f = 870 to 914 MHz	12	_	-	dB
S <sub>22</sub>	output return losses	f = 40 to 80 MHz	23	_	-	dB
		f = 80 to 160 MHz	22	_	_	dB
		f = 160 to 320 MHz	18	-	-	dB
		f = 320 to 550 MHz	17	_	_	dB
		f = 550 to 650 MHz	17	_	_	dB
		f = 650 to 750 MHz	17	_	-	dB
		f = 750 to 870 MHz	14	_	-	dB
		f = 870 to 914 MHz	12	_	_	dB
s <sub>21</sub>	phase response	f = 50 MHz	-45	_	+45	deg
СТВ	composite triple beat	79 chs flat; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 331.25 MHz	_	_	-63.5	dB
		132 chs flat; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 445.25 MHz	_	_	-57.5	dB
X <sub>mod</sub>	cross modulation	79 chs flat; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 55.25 MHz	_	_	-57	dB
		132 chs flat; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 55.25 MHz	_	_	-51	dB
CSO	composite second order distortion	79 chs flat; V <sub>o</sub> = 44 dBmV; f <sub>m</sub> = 54.0 MHz	_	_	-64	dB
		132 chs flat; $V_0 = 44 \text{ dBmV}$ ; $f_m = 860.5 \text{ MHz}$	_	_	-58	dB
NF	noise figure	f = 50 MHz	_	_	5	dB
		f = 550 MHz	_	_	5	dB
		f = 750 MHz	_	_	5	dB
		f = 870 MHz	_	_	5	dB
d <sub>2</sub>	second order distortion	note 1	_	_	-60	dB
		note 2	_	_	-57	dB

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SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Vo	output voltage	$d_{im} = -60 \text{ dB}$ ; note 3	66	_	_	dBmV
		$d_{im} = -60 \text{ dB}$ ; note 4	64	_	_	dBmV
I <sub>tot</sub>	total current consumption (DC)	note 5	295	310	325	mA

#### **Notes**

- 1.  $f_p = 55.25 \text{ MHz}$ ;  $V_p = 60 \text{ dBmV}$ ;  $f_q = 493.25 \text{ MHz}$ ;  $V_q = 60 \text{ dBmV}$ ; measured at  $f_p + f_q = 548.5 \text{ MHz}$ .
- 2.  $f_p$  = 55.25 MHz;  $V_p$  = 60 dBmV;  $f_q$  = 805.25 MHz;  $V_q$  = 60 dBmV; measured at  $f_p$  +  $f_q$  = 860.5 MHz.
- 3. Measured according to DIN45004B:  $f_p$  = 540.25 MHz;  $V_p$  =  $V_o$ ;  $f_q$  = 547.25 MHz;  $V_q$  =  $V_o$  -6 dB;  $f_r$  = 549.25 MHz;  $V_r$  =  $V_o$  -6 dB; measured at  $f_p$  +  $f_q$   $f_r$  = 538.25 MHz.
- 4. Measured according to DIN45004B:  $f_p$  = 851.25 MHz;  $V_p$  =  $V_o$ ;  $f_q$  = 858.25 MHz;  $V_q$  =  $V_o$  –6 dB;  $f_r$  = 860.25 MHz;  $V_r$  =  $V_o$  –6 dB; measured at  $f_p$  +  $f_q$   $f_r$  = 849.25 MHz.
- 5. The module normally operates at  $V_B = 24 \text{ V}$ , but is able to withstand supply transients up to 30 V.

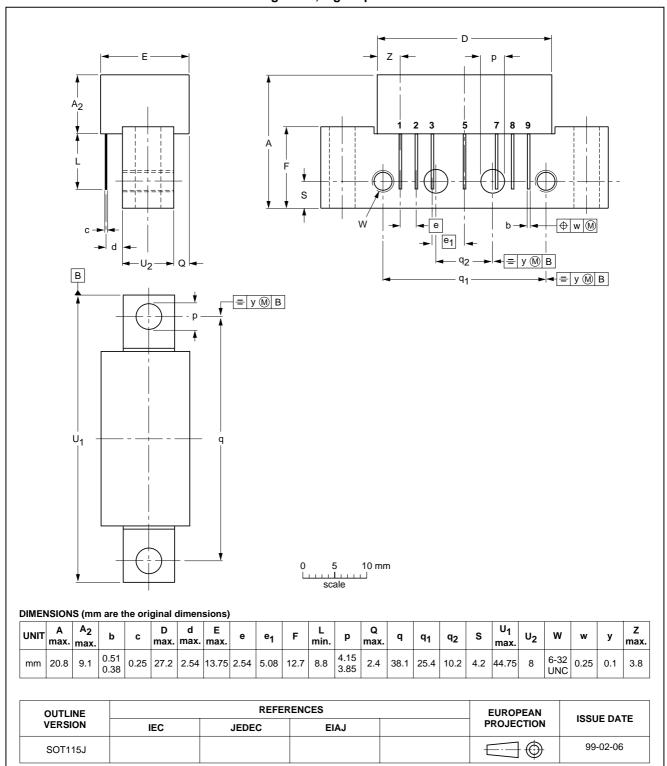
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#### **PACKAGE OUTLINE**

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J



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NOTES

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